

Single Zener diodes Rev. 4 — 28 November 2011

Product data sheet

1. Product profile

1.1 General description

General-purpose Zener diodes in a SOD27 (SC-40) small hermetically sealed glass package.

1.2 Features and benefits

- Total power dissipation: P_{tot} ≤ 500 mW
- Low differential resistance
- Low leakage current

1.3 Applications

General regulation functions

1.4 Quick reference data

Table 1.Quick reference data

| $T_j = 25 \ ^{\circ}C$ | unless otherwise specifi | ied. | | | | |
|------------------------|--------------------------|-------------------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V_{F} | forward voltage | I _F = 200 mA | <u>[1]</u> - | - | 1.5 | V |

 $\label{eq:point} \begin{tabular}{ll} \begin{$

2. Pinning information

| Table 2. Pin | Pinning | Cimplified outline | Cranhia aymhal |
|-----------------|-------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | cathode | [1] | |
| 2 | anode | | 1 2 |
| | | | 006aaa152 |

[1] The marking band indicates the cathode.



Single Zener diodes

3. Ordering information

| Table 3. Ordering inf | ormation | | |
|----------------------------------|----------|---|---------|
| Type number | Package | | |
| | Name | Description | Version |
| NZX2V1B to NZX36X ^[1] | SC-40 | hermetically sealed glass package; axial leaded; 2 leads | SOD27 |

[1] The series consists of 112 types with nominal working voltages from 2.1 V to 36 V.

4. Marking

| Table 4. Marking codes | |
|--------------------------|-----------------------------|
| Type number | Marking code |
| NZX2V1B to NZX36X | the diodes are type branded |

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Мах | Unit |
|------------------|-------------------------|-----------------------------|-----|------|------|
| I _F | forward current | | - | 250 | mA |
| P _{tot} | total power dissipation | $T_{tp} \le 25 \ ^{\circ}C$ | - | 500 | mW |
| Tj | junction temperature | | - | 175 | °C |
| T _{amb} | ambient temperature | | -55 | +175 | °C |
| T _{stg} | storage temperature | | -65 | +175 | °C |

6. Thermal characteristics

Table 6. Thermal characteristics

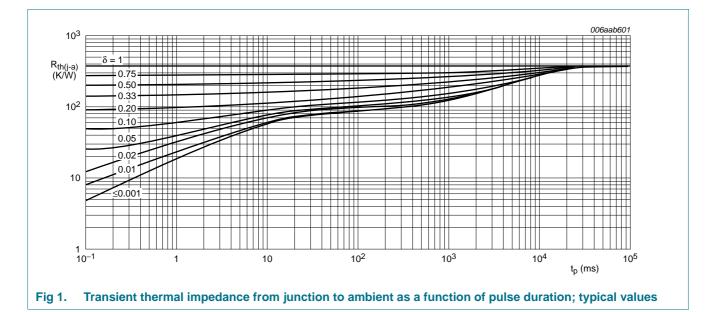
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|-------------|--------------|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1]</u> _ | - | 380 | K/W |
| R _{th(j-t)} | thermal resistance from junction to tie-point | | <u>[1]</u> - | - | 300 | K/W |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB) without metallization pad; maximum lead length 8 mm.

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Characteristics 7.

Table 7. **Characteristics**

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|-----------------|-------------------------|--------------|-----|-----|------|
| V _F | forward voltage | I _F = 200 mA | <u>[1]</u> _ | - | 1.5 | V |

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

Table 8. Characteristics per type; NZX2V1B to NZX18C

| $T_{i} = 25$ | ℃ unless | otherwise | specified. |
|--------------|----------|-----------|------------|
|--------------|----------|-----------|------------|

| NZXxxx | Sel | Working V _Z (V) | l voltage | Differential resistance r _{dif} (Ω) | Reverse I _R (μΑ) | current |
|--------|---------------|-------------------------------|-----------|--|--------------------------------|--------------------|
| | | I _Z = 5 m/ | A | I _Z = 5 mA | _ | |
| | | Min | Max | Max | Max | V _R (V) |
| 2V1 | В | 2.0 | 2.2 | 100 | 5 | 0.5 |
| 2V4 | А | 2.3 | 2.5 | 100 | 50 | 1 |
| | В | 2.4 | 2.6 | | | |
| 2V7 | A 2.5 2.7 100 | 100 | 20 | 1 | | |
| | В | 2.6 | 2.8 | | | |
| | С | 2.7 | 2.9 | | | |
| V0 | А | 2.8 | 3.0 | 100 | 10 | 1 |
| | В | 2.9 | 3.1 | | | |
| | С | 3.0 | 3.2 | | | |
| SV3 | А | 3.1 | 3.3 | 100 | 5 | 1 |
| | В | 3.2 | 3.4 | | | |
| | С | 3.3 | 3.5 | | | |

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| NZXxxx | Sel | Working V _Z (V) | y voltage | Differential resistance r _{dif} (Ω) | Reverse I _R (μΑ) | current |
|--------|-----|-------------------------------|-----------|--|--------------------------------|--------------------|
| | | I _Z = 5 m | Α | I _Z = 5 mA | | |
| | | Min | Max | Max | Max | V _R (V) |
| 3V6 | А | 3.4 | 3.6 | 100 | 5 | 1 |
| | В | 3.5 | 3.7 | | | |
| | С | 3.6 | 3.8 | | | |
| 3V9 | А | 3.7 | 3.9 | 100 | 3 | 1 |
| | В | 3.8 | 4.0 | | | |
| | С | 3.9 | 4.1 | | | |
| 4V3 | А | 4.0 | 4.2 | 100 | 3 | 1 |
| | В | 4.1 | 4.3 | | | |
| | С | 4.2 | 4.4 | | | |
| | D | 4.3 | 4.5 | | | |
| 4V7 | А | 4.4 | 4.6 | 100 | 3 2 | 2 |
| | В | 4.5 | 4.7 | | | |
| | С | 4.6 | 4.8 | | | |
| | D | 4.7 | 4.9 | | | |
| 5V1 | А | 4.8 | 5.0 | 100 | 2 | 2 |
| | В | 4.9 | 5.1 | | | |
| | С | 5.0 | 5.2 | | | |
| | D | 5.1 | 5.3 | | | |
| 5V6 | А | 5.2 | 5.5 | 40 | 1 | 2 |
| | В | 5.3 | 5.6 | | | |
| | С | 5.4 | 5.7 | | | |
| | D | 5.5 | 5.8 | | | |
| | E | 5.6 | 5.9 | | | |
| 6V2 | А | 5.7 | 6.0 | 15 | 3 | 4 |
| | В | 5.8 | 6.1 | | | |
| | С | 6.0 | 6.3 | | | |
| | D | 6.1 | 6.4 | | | |
| | E | 6.3 | 6.6 | | | |
| 6V8 | А | 6.4 | 6.7 | 15 | 2 | 4 |
| | В | 6.6 | 6.9 | | | |
| | С | 6.7 | 7.0 | | | |
| | D | 6.9 | 7.2 | | | |

Table 8.Characteristics per type; NZX2V1B to NZX18C ... continued $T_i = 25$ °C unless otherwise specified

Single Zener diodes

| NZXxxx | Sel | Working V _Z (V) | Working voltage V _Z (V) | | Reverse current I _R (μΑ) | | | |
|--------|-----|-------------------------------|---------------------------------------|-----------------------|--|--------------------|--|--|
| | | I _Z = 5 mA | A | I _Z = 5 mA | | | | |
| | | Min | Max | Max | Max | V _R (V) | | |
| 7V5 | A | 7.0 | 7.3 | 15 | 1 | 5 | | |
| | В | 7.2 | 7.6 | | | | | |
| | С | 7.3 | 7.7 | | | | | |
| | D | 7.5 | 7.9 | | | | | |
| | Х | 7.07 | 7.45 | | | | | |
| 8V2 | А | 7.7 | 8.1 | 20 | 0.7 | 5 | | |
| | В | 7.9 | 8.3 | | | | | |
| | С | 8.1 | 8.5 | | | | | |
| | D | 8.3 | 8.7 | | | | | |
| 9V1 | А | 8.5 | 8.9 | 20 | 0.5 | 6 | | |
| | В | 8.7 | 9.1 | | | | | |
| | С | 8.9 | 9.3 | | | | | |
| | D | 9.1 | 9.5 | | | | | |
| | E | 9.3 | 9.7 | | | | | |
| 10 | А | 9.5 | 9.9 | 25 | 0.2 | 7 | | |
| | В | 9.7 | 10.1 | | | | | |
| | С | 9.9 | 10.3 | | | | | |
| | D | 10.2 | 10.6 | | | | | |
| 11 | А | 10.4 | 10.8 | 25 | 0.1 | 8 | | |
| | В | 10.7 | 11.1 | | | | | |
| | С | 10.9 | 11.3 | | | | | |
| | D | 11.1 | 11.6 | | | | | |
| 12 | А | 11.4 | 11.9 | 35 | 0.1 | 8 | | |
| | В | 11.6 | 12.1 | | | | | |
| | С | 11.9 | 12.4 | | | | | |
| | D | 12.2 | 12.7 | | | | | |
| | Х | 11.44 | 12.03 | | | | | |
| 13 | А | 12.4 | 12.9 | 35 | 0.1 | 8 | | |
| | В | 12.6 | 13.1 | | | | | |
| | С | 12.9 | 13.4 | | | | | |
| 14 | А | 13.2 | 13.7 | 35 | 0.05 | 9.8 | | |
| | В | 13.5 | 14.0 | | | | | |
| | С | 13.8 | 14.3 | | | | | |

Table 8. Characteristics per type; NZX2V1B to NZX18C ... continued $T_i = 25$ °C unless otherwise specified.

Single Zener diodes

| NZXxxx | Sel | Working V _Z (V) | voltage | Differential resistance r _{dif} (Ω) | Reverse I _R (μΑ) | current |
|--------|-----|-------------------------------|---------|--|--------------------------------|--------------------|
| | | I _Z = 5 mA | | I _Z = 5 mA | | |
| | | Min | Max | Max | Max | V _R (V) |
| 15 | А | 14.1 | 14.7 | 40 | 0.05 | 10.5 |
| | В | 14.5 | 15.1 | | | |
| | С | 14.9 | 15.5 | | | |
| | Х | 14.35 | 15.09 | | | |
| 6 | А | 15.3 | 15.9 | 45 | 0.05 | 11.2 |
| | В | 15.7 | 16.5 | | | |
| | С | 16.3 | 17.1 | | | |
| 18 | А | 16.9 | 17.7 | 55 | 0.05 | 12.6 |
| | В | 17.5 | 18.3 | | | |
| | С | 18.1 | 19.0 | | | |

Table 8. Characteristics per type; NZX2V1B to NZX18C ... continued



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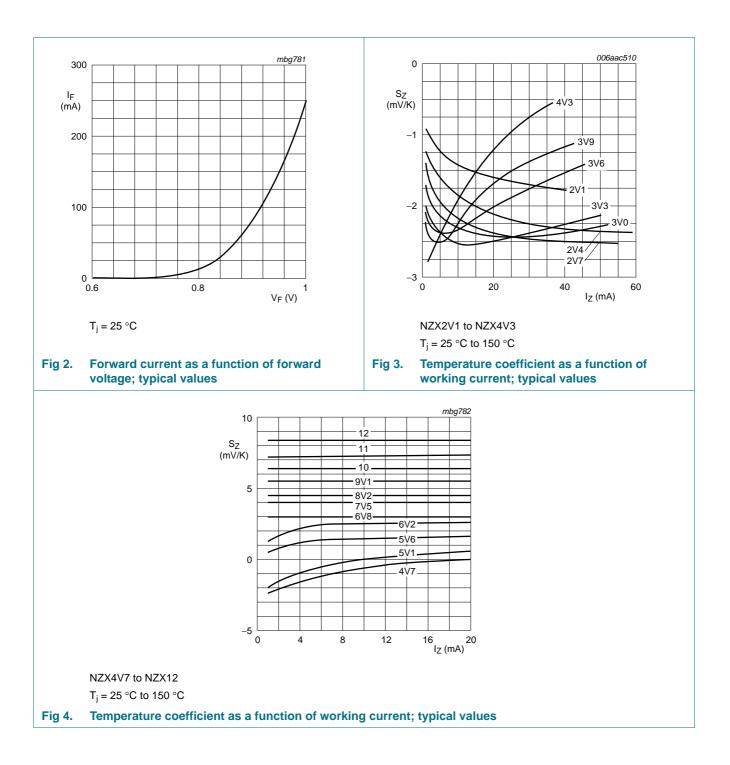
| NZXxxx | Sel | Working voltage V _Z (V) I _Z = 2 mA | | Differential resistance r _{dif} (Ω) | Reverse current I _R (μΑ) | |
|--------|-----|--|-------|--|--|--------------------|
| | | | | I _Z = 2 mA | | |
| | | Min | Max | Max | Max | V _R (V) |
| 20 | А | 18.8 | 19.7 | 60 | 0.05 | 14 |
| | В | 19.5 | 20.4 | | | |
| | С | 20.2 | 21.2 | | | |
| 22 | А | 20.9 | 21.9 | 65 | 0.05 | 15.4 |
| | В | 21.6 | 22.6 | | | |
| | С | 22.3 | 23.3 | | | |
| 24 | А | 22.9 | 24.0 | 70 | 0.05 16.8 | 16.8 |
| | В | 23.6 | 24.7 | | | |
| | С | 24.3 | 25.5 | | | |
| | Х | 22.61 | 23.77 | | | |
| 27 | А | 25.2 | 26.6 | 80 | 0.05 | 18.9 |
| | В | 26.2 | 27.6 | | | |
| | С | 27.2 | 28.6 | | | |
| | Х | 26.99 | 28.39 | | | |
| 30 | А | 28.2 | 29.6 | 100 | 0.05 | 21 |
| | В | 29.2 | 30.6 | | | |
| | С | 30.2 | 31.6 | | | |
| | Х | 29.02 | 30.51 | | | |
| 33 | А | 31.2 | 32.6 | 120 | 0.05 | 23.1 |
| | В | 32.2 | 33.6 | | | |
| | С | 33.2 | 34.5 | | | |
| 36 | А | 34.2 | 35.7 | 140 | 0.05 | 25.2 |
| | В | 35.3 | 36.8 | | | |
| | С | 36.4 | 38.0 | | | |
| | Х | 35.36 | 37.19 | | | |

Table 9.Characteristics per type; NZX20A to NZX36X $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

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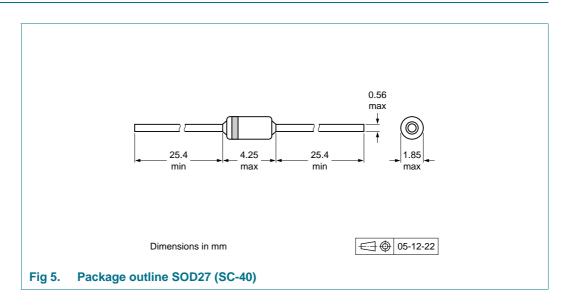
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8. Package outline



9. Packing information

Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number ^[2] | Package | Description | Packing quantity | |
|----------------------------|---------|----------------------------|------------------|-------|
| | | | 5000 | 10000 |
| NZX2V1B to NZX36X | SOD27 | 26 mm tape ammopack, axial | -143 | - |
| | | 52 mm tape ammopack, axial | - | -133 |
| | | 52 mm reel pack, axial | - | -113 |

[1] For further information and the availability of packing methods, see <u>Section 12</u>.

[2] The series consists of 112 types with nominal working voltages from 2.1 V to 36 V.

10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|-----------------------------------|----------------------------|---------------|-------------|
| NZX_SER v.4 | 20111128 | Product data sheet | - | NZX_SER v.3 |
| Modifications: | • Section 1.2: | corrected. | | |
| | Section 11 "L | egal information": updated | | |
| NZX_SER v.3 | 20110121 | Product data sheet | - | NZX_SER v.2 |
| NZX_SER v.2 | 20090603 | Product data sheet | - | NZX_SER v.1 |
| NZX SER v.1 | 20080724 | Product data sheet | - | - |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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